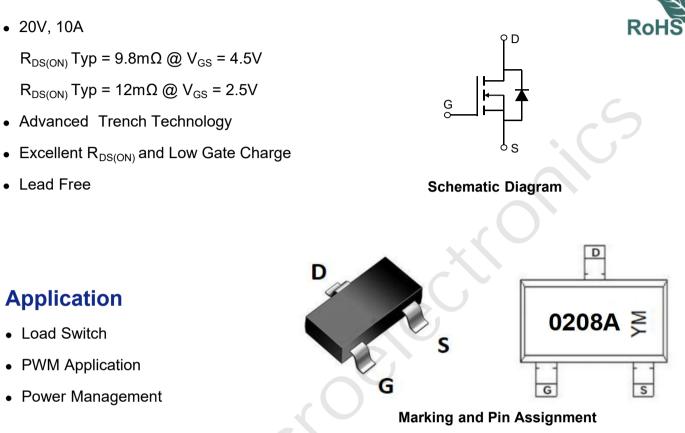


N-Channel 20V, 9.8mΩ Typ. Power MOSFET

Description





Package Marking and Ordering Information

Device	Marking	Package	Outline	Reel Size	Reel (pcs)	Per Carton (pcs)
CRMJTU0208A	0208A	SOT-23-3L	TAPING	7"	3000	120000

Absolute Maximum Ratings (@ T_J = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V _{DS}	Drain-to-Source Voltage		20	V
V _{GS}	Gate-to-Source Voltage		±12	V
	Continuous Drain Current	T _A = 25°C	10	А
Ι _D		T _A = 100°C	6	А
I _{DM}	Pulsed Drain Current ⁽¹⁾		40	А
P _D	Power Dissipation	T _A = 25°C	2	W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient ⁽²⁾		62.5	°C/W
T _J , T _{stg}	Junction & Storage Temperature Rang	e	-55 to 150	°C



Electrical Characteristics ($T_J = 25^{\circ}C$ unless otherwise specified)

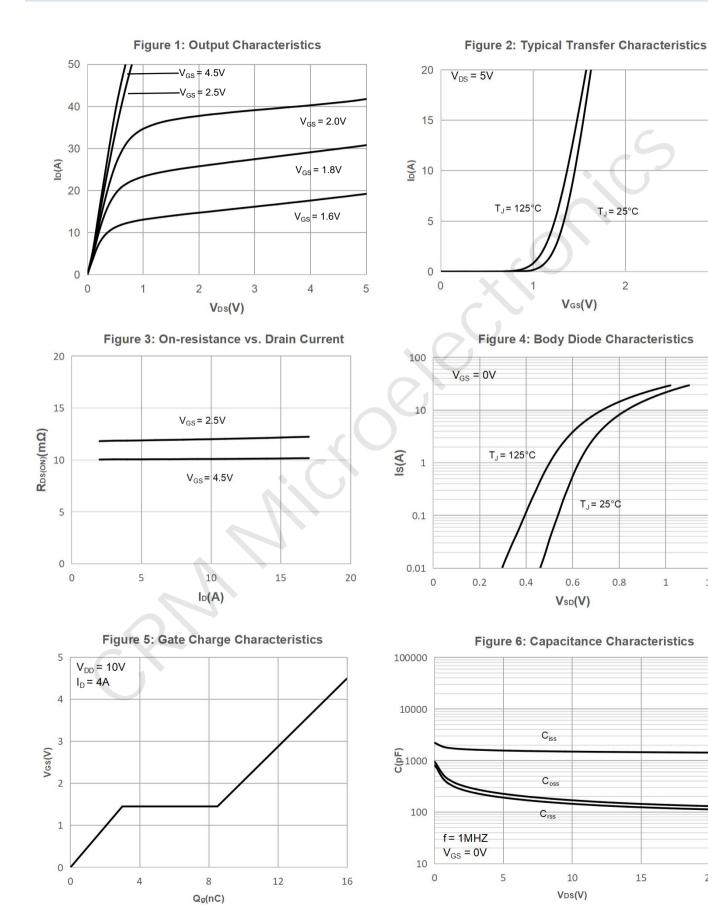
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Chara	acteristics					
V _{(BR)DSS}	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	20	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 20V, V _{GS} = 0V	-	-	1.0	μA
I _{GSS}	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 12V$	-	-	±100	nA
On Chara	acteristics				6	
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS} , I_D = 250 μ A	0.4	0.7	1.2	V
R _{DS(ON)}	Static Drain-Source ON-Resistance ⁽³⁾	$V_{GS} = 4.5V, I_{D} = 5A$	-	9.8	12.7	mΩ
		V _{GS} = 2.5V, I _D = 3A	-	12	15.6	mΩ
Dynamic	Characteristics					
C _{iss}	Input Capacitance		-	1480	-	pF
C _{oss}	Output Capacitance	V _{GS} = 0V, V _{DS} = 10V, f = 1MHz	X-\	170	-	pF
C _{rss}	Reverse Transfer Capacitance			146	-	pF
Q_{g}	Total Gate Charge	$V_{GS} = 0$ to 4.5V $V_{DS} = 10V$, $I_D = 4A$	<u> </u>	16	-	nC
Q_gs	Gate Source Charge		-	3	-	nC
Q_{gd}	Gate Drain("Miller") Charge	$v_{\rm DS} = 10$ v, $r_{\rm D} = 4$	-	5.5	-	nC
Switchin	g Characteristics					
t _{d(on)}	Turn-On DelayTime	. C	-	10	-	ns
t _r	Turn-On Rise Time	V _{GS} = 4.5V, V _{DD} = 10V	-	30	-	ns
$t_{d(off)}$	Turn-Off DelayTime	I_D = 4A, R_{GEN} = 3 Ω	-	40	-	ns
t _f	Turn-Off Fall Time		-	16	-	ns
Drain-So	urce Diode Characteristics and I	Max Ratings				
I _S	Maximum Continuous Drain to Source Diode Forward Current			-	10	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	40	А
V _{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _S = 10A	-	-	1.2	V
lotes:	1. Repetitive Rating: Pulse Width Limited by Maxin	num Junction Temperature.				

2. $R_{\theta JA}$ is measured with the device mounted on a 1inch² pad of 2oz copper FR4 PCB

3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%.



Typical Performance Characteristics



20

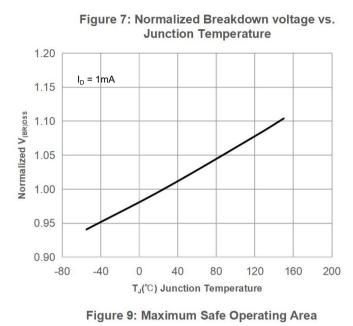
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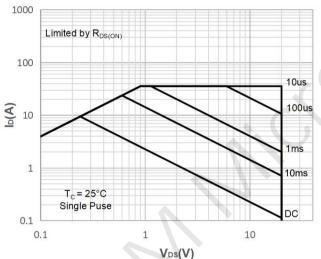
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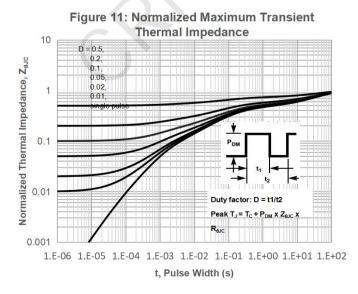


CRMJTU0208A N-Channel 20V, 9.8mΩ Typ. Power MOSFET

Typical Performance Characteristics







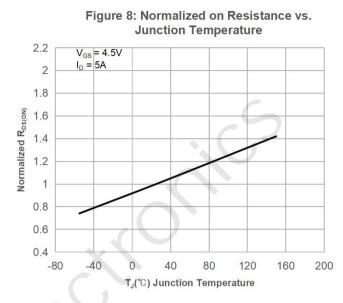


Figure 10: Maximum Continuous Drian Current vs. Case Temperature

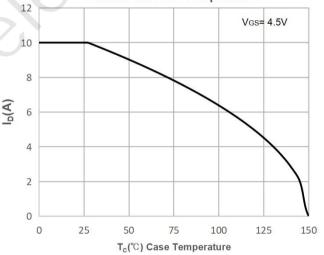
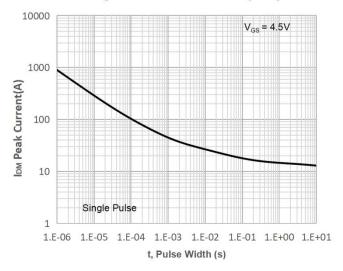


Figure 12: Peak Current Capacity

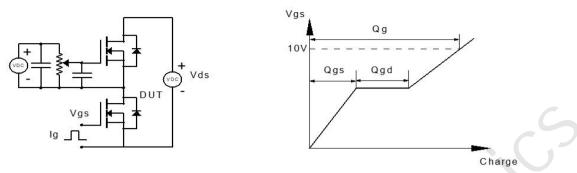


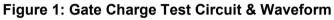


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Test Circuit





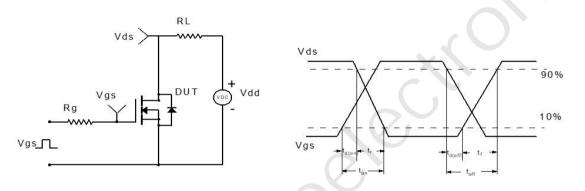
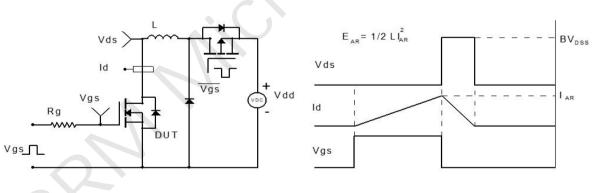


Figure 2: Resistive Switching Test Circuit & Waveform





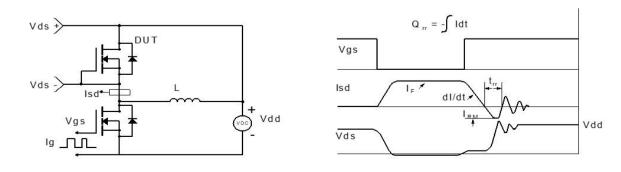
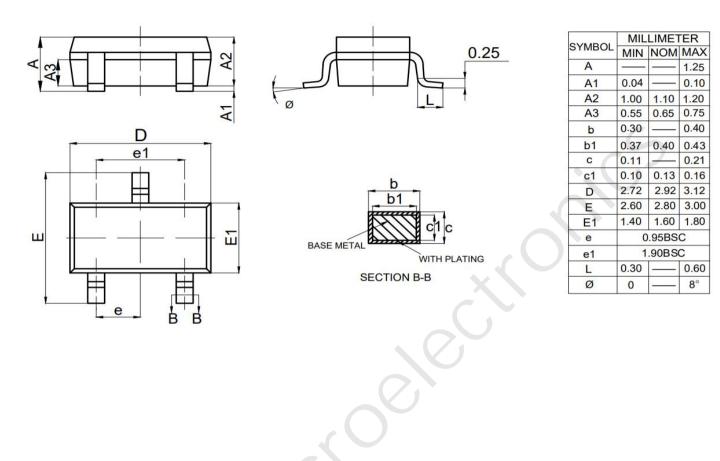


Figure 4: Diode Recovery Test Circuit & Waveform



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Package Mechanical Data(SOT-23-3L)



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